

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
30V	6m Ω @10V	28A
	9.4m Ω @4.5V	

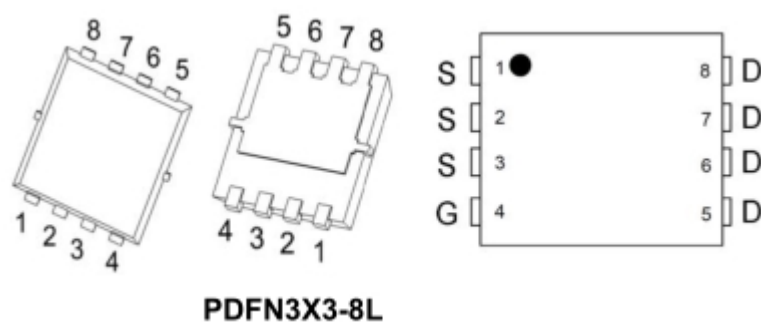
Feature

- Fast Switching
- Low Gate Charge and Rdson
- Low Reverse transfer capacitances
- 100% Single Pulse avalanche energy Test

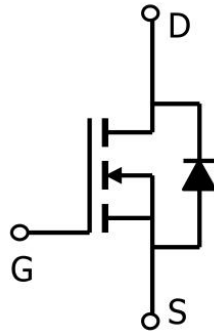
Application

- Power switching application
- Isolated DC/DC Converters in Telecom and Industrial

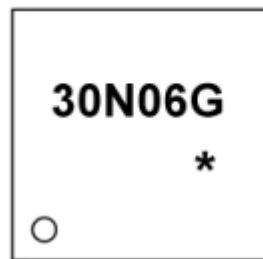
Package



Circuit diagram



Marking



30N06G =Device Code
* =Month Code

Absolute maximum ratings

(T_a=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current, VGS @ 10V ¹	I _D @T _C =25°C	28	A
Continuous Drain Current, VGS @ 10V ¹	I _D @T _C =100°C	20	A
Pulsed Drain Current ²	I _{DM}	100	A
Single Pulse Avalanche Energy ³	E _{AS}	39.2	mJ
Avalanche Current	I _{AS}	28	A
Total Power Dissipation ⁴	P _D @T _C =25°C	21	W
Thermal Resistance Junction-Ambient ¹	R _{θJA}	65	°C/W
Thermal Resistance Junction-Case ¹	R _{θJC}	6	°C/W
Storage Temperature Range	T _{STG}	-55 to 150	°C
Operating Junction Temperature Range	T _J	-55 to 150	°C

Electrical characteristics

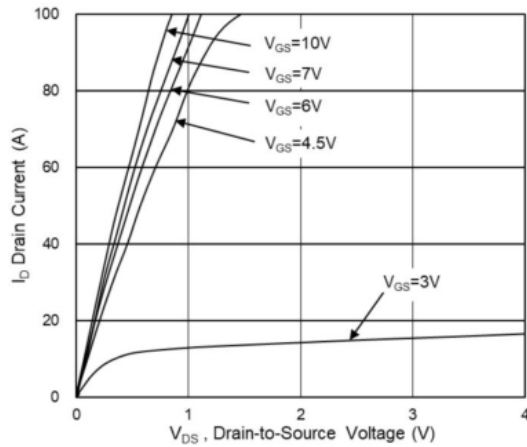
(T_A=25°C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV (BR)DSS	V _{GS} = 0V, I _D =250μA	30			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =30V, V _{GS} = 0V, T _J =25°C			1	uA
Drain-Source Leakage Current	I _{DSS}	V _{DS} =30V, V _{GS} = 0V, T _J =55°C			5	uA
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V,V _{GS} =±20V			±100	uA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.2	1.7	2.2	V
Static Drain-Source On-Resistance ²	R _{DS(on)}	V _{GS} =10V, I _D =12A		6	8	mΩ
		V _{GS} =4.5V, I _D =12A		9.4	11	
Gate Threshold Voltage	R _g	V _{DS} =0V, V _{GS} =0V, f=1MHz	0.8	1.7	2.6	Ω
Dynamic Characteristics						
Forward Transconductance	g _{fs}	V _{DS} =5V, I _D =12A		55		S
Total Gate Charge (4.5V)	Q _g	V _{DS} =15V, V _{GS} =10V, I _D =12A		7.1		pF
Gate-Source Charge	Q _{gs}			2.2		
Gate-Drain Charge	Q _{gd}			3.1		
Input Capacitance	C _{iss}	V _{DS} =15V, V _{GS} =0V, f=1MHz		693		pF
Output Capacitance	C _{oss}			332		
Reverse Transfer Capacitance	C _{rss}			34		
Switching Characteristics ⁴						
Turn-On Delay Time	T _{d(on)}	V _{DD} =15V, V _{GS} =10V, R _G =3Ω, I _D =12A		7		nS
Rise Time	T _r			18.8		
Turn-Off Delay Time	T _{d(off)}			19.5		
Fall Time	T _f			3.4		
Drain-Source Diode Characteristics						
Continuous Source Current ^{1,5}	I _S	V _G =V _D =0V , Force Current			12	A
Diode Forward Voltage ²	V _{SD}	V _{GS} =0V , I _S =1A , T _J =25°C			1	V

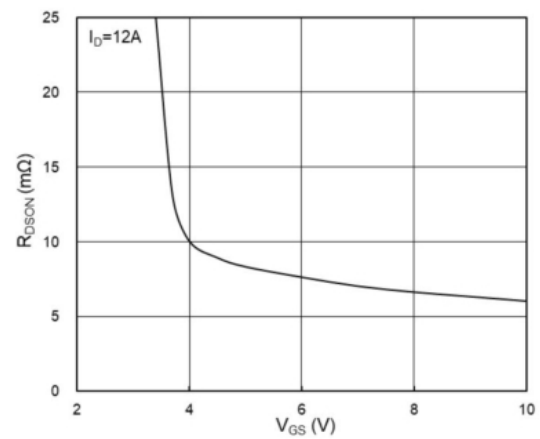
Notes:

1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
2. The data tested by pulsed, pulse width ≤ 300μs, duty cycle ≤ 2%
3. The EAS data shows Max. rating. The test condition is V_{DD} = 25V, V_{GS} = 10V, L = 0.1mH, I_{AS} = 28A
4. The power dissipation is limited by 150°C junction temperature
5. The data is theoretically the same as I_D and I_{DM}, in real applications, should be limited by total power dissipation.

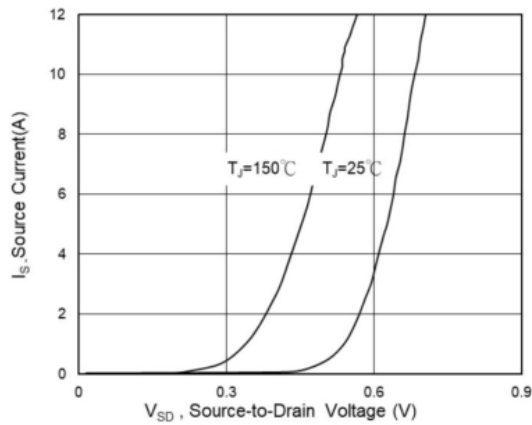
Typical Characteristics



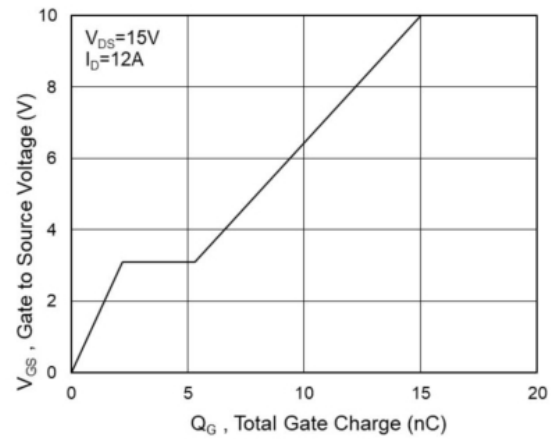
Typical Output Characteristics



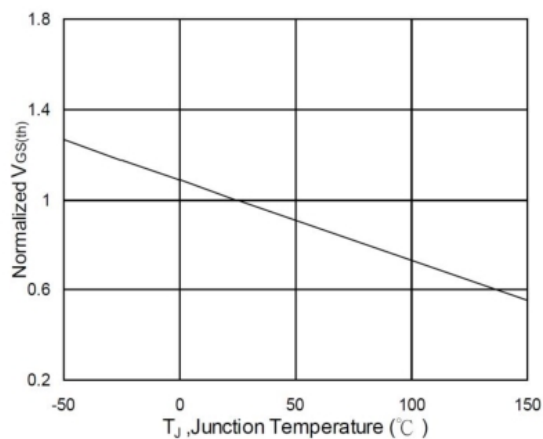
On-Resistance vs G-S Voltage



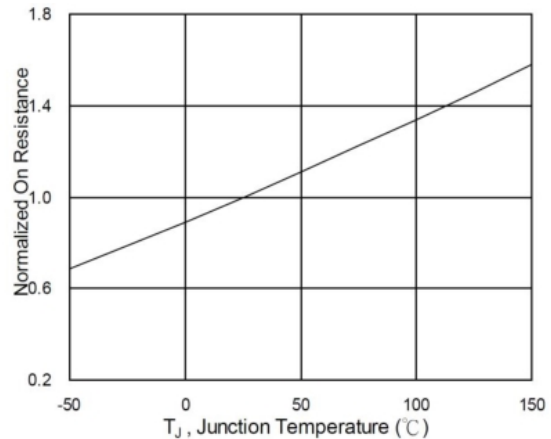
Source Drain Forward Characteristics



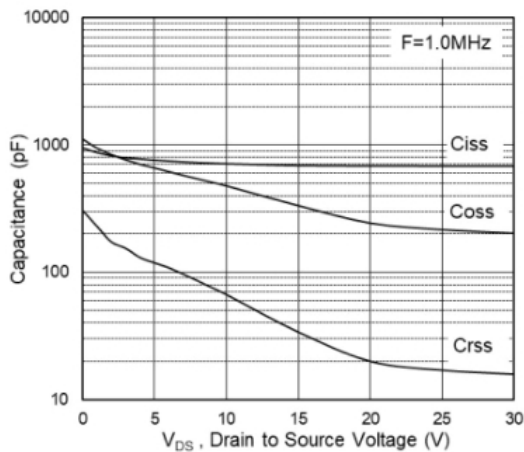
Gate-Charge Characteristics



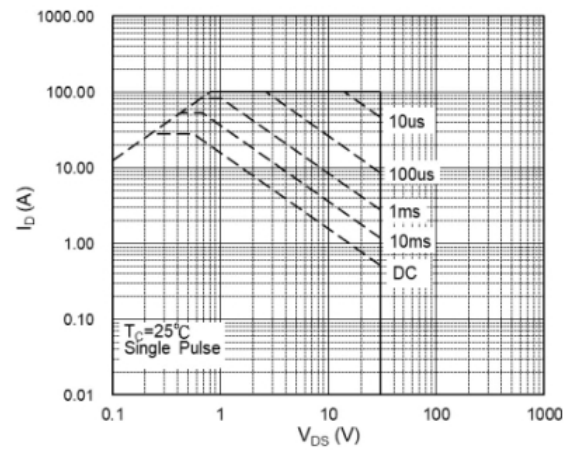
Normalized $V_{GS(th)}$ vs T_J



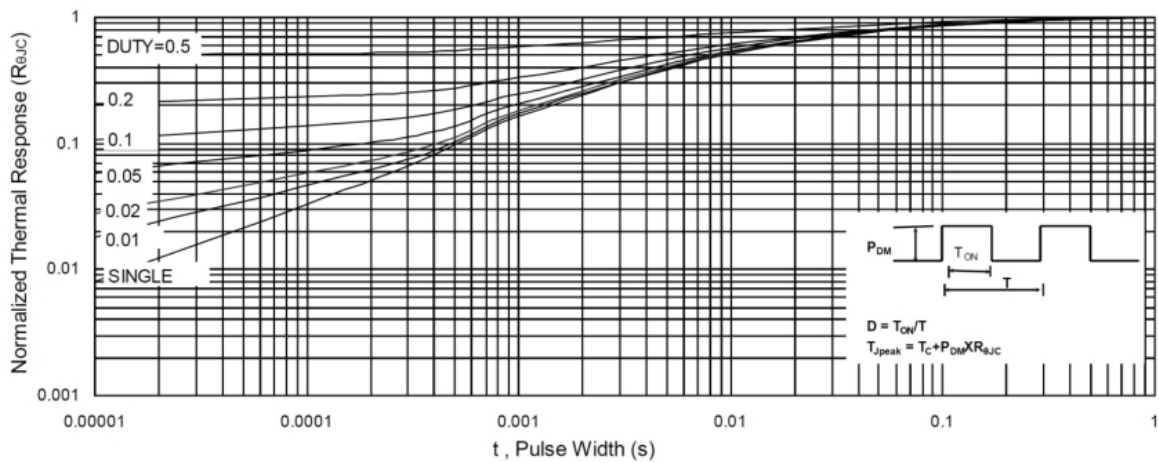
Normalized $R_{DS(on)}$ vs T_J



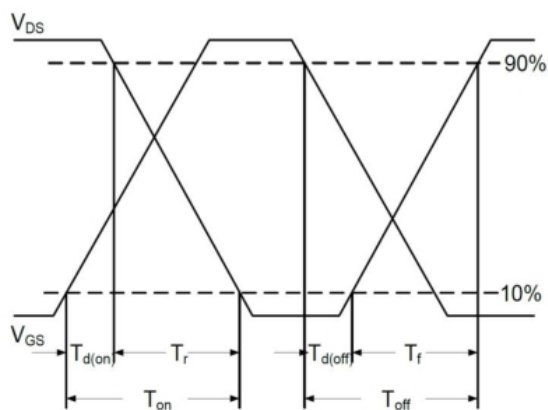
Capacitance



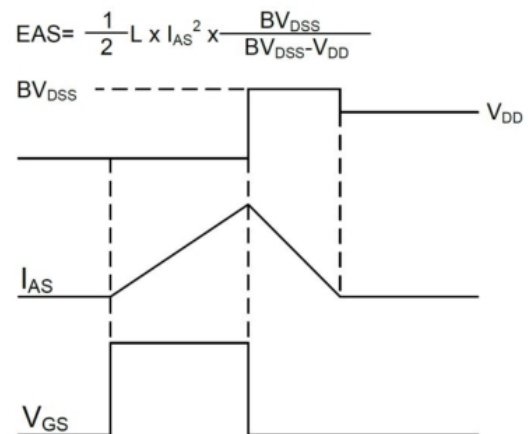
Safe Operating Area



Normalized Maximum Transient Thermal Impedance

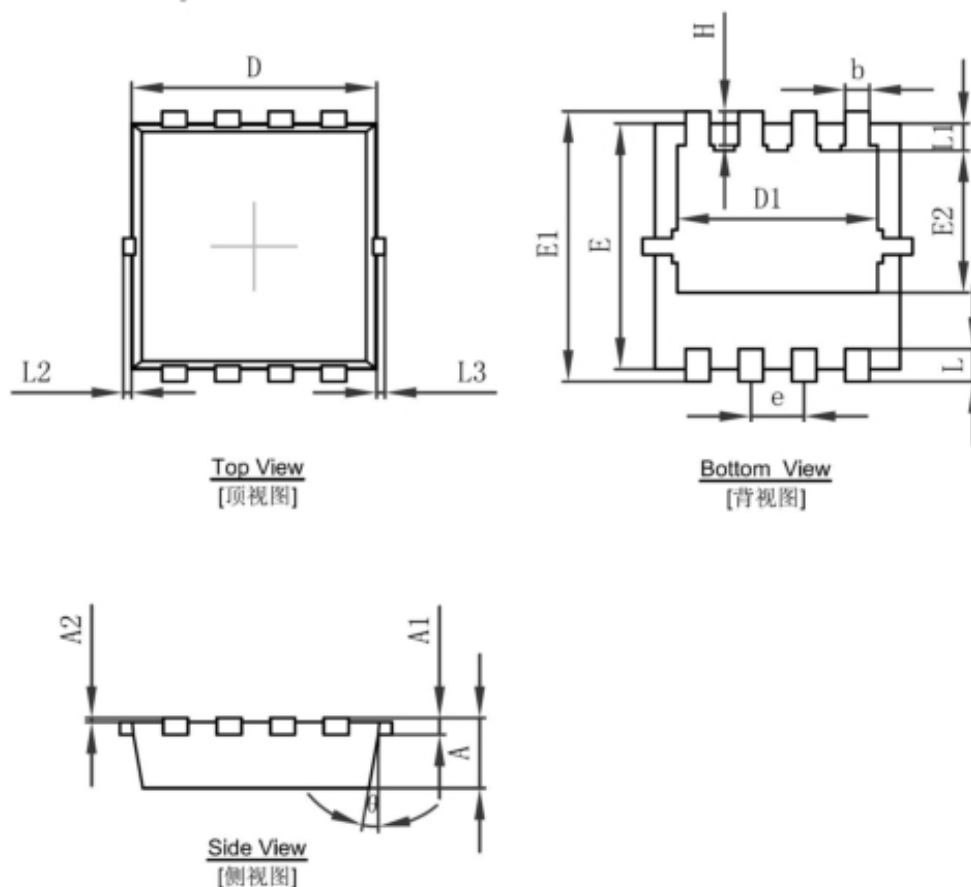


Switching Time Waveform



Unclamped Inductive Switching Waveform

PDFN3X3-8L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.650	0.850	0.026	0.033
A1	0.152 REF.		0.006 REF.	
A2	0~0.05		0~0.002	
D	2.900	3.100	0.114	0.122
D1	2.300	2.600	0.091	0.102
E	2.900	3.100	0.114	0.122
E1	3.150	3.450	0.124	0.136
E2	1.535	1.935	0.060	0.076
b	0.200	0.400	0.008	0.016
e	0.550	0.750	0.022	0.030
L	0.300	0.500	0.012	0.020
L1	0.180	0.480	0.007	0.019
L2	0~0.100		0~0.004	
L3	0~0.100		0~0.004	
H	0.315	0.515	0.012	0.020
θ	9°	13°	9°	13°